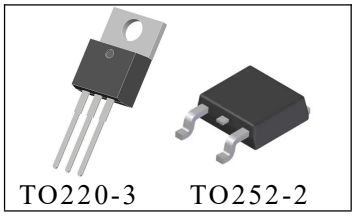
Silicore
芯谷科技

D78XXD

3-Terminal 1.2A Positive Voltage Regulator

General Description

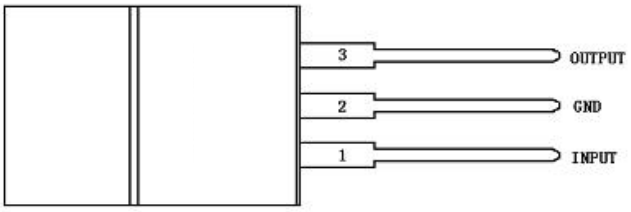


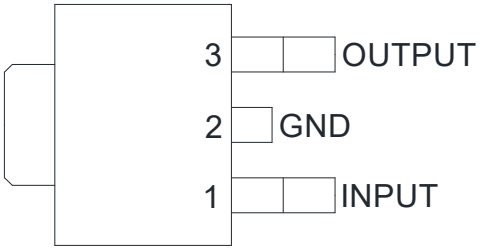
The D78XXD series of three-terminal positive regulator are available in the TO220-3 and TO252-2 package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 1.2A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltages and currents.

Features

- Output Current up to 1.2A
- Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating Area Protection
- Output Voltages : D7805D: 5V D7806D: 6V D7808D: 8V
  D7809D: 9V D7812D: 12V D7815D:15V

Pin Configuration



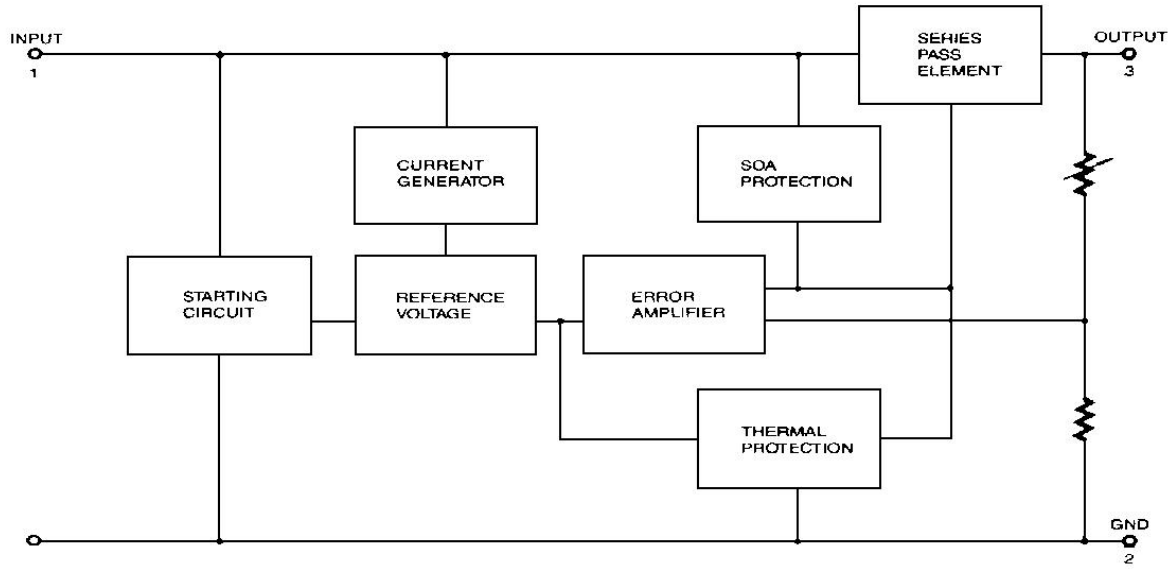


Package Information

Part NO.	Order NO	PACKAG DESCRIPTION	PACKAGE MARKING	PACKAGE OPTION
D78XXD	D78XXDT	TO220-3	CHMC D78XXD SXXXX	50/Tube
D78XXD	D78XXD	TO252-2		70/Tube 2500/Reel

CHMC:Trademark D78XXD:Part NO. (XX: Voltage) SXXXX:Lot NO.

Block Diagram



Absolute Maximum Ratings (Ta=25℃)

Characteristics	Symbol	Value	Units
Input Voltage	Vi	35	V
Thermal Resistance Junction-Case	$R_{\theta JC}$	(TO220-3)5 (TO252-2)12	℃/W
Thermal Resistance Junction-Air	$R_{\theta JA}$	(TO220-3)65 (TO252-2)112	℃/W
Operating Temperature Range	T_{OPR}	-40~+125	℃
Storage Temperature Range	T_{STG}	-55~+150	℃

D7805D Electrical Characteristics

(Refer to the test circuit, -40°C＜T_J＜125°C ,Io=500mA, Vi=10V, Ci=0.33μF, Co=0.1μF, unless otherwise specified

Characteristics	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	Vo	T_J=+25°C		4.8	5.0	5.2	V
		5.0mA≤Io≤1.0A,Po≤15W Vi=7V to 20V		4.75	5.0	5.25	
Line Regulation*	Regline	T_J=+25°C	Vi=7V to 25V		4.0	100	mV
			Vi=8V to 12V		1.6	50	
Load Regulation*	Regload	T_J=+25°C	Io=5.0mA to 1.2A		15	100	mV
			Io=250mA to 600mA		4	50	
Quiescent Current	I_Q	T_J=+25°C			5.0	8.0	mA
Quiescent Current Change	ΔI_Q	Io=5.0mA to 1.0A			0.03	0.5	mA
		Vi=7V to 25V			0.3	1.3	
Output Voltage Drift	$\Delta Vo/\Delta T$	Io=5.0mA			-0.8		mV/°C
Output Noise Voltage	V_N	f=10Hz to 100KHz,T_A=+25°C			42		μV/Vo
Ripple Rejection	RR	f=120Hz Vi=8V to 18V		62	73		dB
Dropout Voltage	VDrop	Io=1A, T_J=+25°C			2		V
Short Circuit Current	I_{SC}	Vi=35V, T_A=+25°C			230		mA
Peak Current	I_{PK}	T_J=+25°C			2.2		A

*Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

D7806D Electrical Characteristics

(Refer to the test circuit, -40°C＜T_J＜125°C ,Io=500mA, Vi=11V, Ci=0.33μF, Co=0.1μF, unless otherwise specified

Characteristics	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	Vo	T_J=+25°C		5.75	6.0	6.25	V
		5.0mA≤Io≤1.0A,Po≤15W Vi=8V to 21V		5.7	6.0	6.3	
Line Regulation*	Regline	T_J=+25°C	Vi=8V to 25V		5.0	120	mV
			Vi=9V to 13V		1.5	60	
Load Regulation*	Regload	T_J=+25°C	Io=5.0mA to 1.2A		9	120	mV
			Io=250mA to 600mA		3	60	
Quiescent Current	I_Q	T_J=+25°C			5.0	8.0	mA
Quiescent Current Change	ΔI_Q	Io=5.0mA to 1.0A				0.5	mA
		Vi=8V to 25V				1.3	
Output Voltage Drift	$\Delta Vo/\Delta T$	Io=5.0mA			-0.8		mV/°C
Output Noise Voltage	V_N	f=10Hz to 100KHz,T_A=+25°C			45		μV/Vo
Ripple Rejection	RR	f=120Hz Vi=9V to 19V		59	75		dB
Dropout Voltage	VDrop	Io=1A, T_J=+25°C			2		V
Short Circuit Current	I_{SC}	Vi=35V, T_A=+25°C			250		mA
Peak Current	I_{PK}	T_J=+25°C			2.2		A

*Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

D7808D Electrical Characteristics

(Refer to the test circuit, -40°C＜T_J＜125°C ,Io=500mA, Vi=14V, Ci=0.33μF, Co=0.1μF, unless otherwise specified

Characteristics	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	Vo	T_J=+25°C		7.7	8.0	8.3	V
		5.0mA≤Io≤1.0A,Po≤15W Vi=10.5V to 23V		7.6	8.0	8.4	
Line Regulation*	Regline	T_J=+25°C	Vi=10.5V to 25V		5.0	160	mV
			Vi=11.5V to 17V		2.0	80	
Load Regulation*	Regload	T_J=+25°C	Io=5.0mA to 1.2A		10	160	mV
			Io=250mA to 600mA		5.0	80	
Quiescent Current	I_Q	T_J=+25°C			5.0	8.0	mA
Quiescent Current Change	ΔI_Q	Io=5.0mA to 1.0A			0.05	0.5	mA
		Vi=10.5V to 25V			0.5	1.0	
Output Voltage Drift	$\Delta Vo/\Delta T$	Io=5.0mA			-0.8		mV/°C
Output Noise Voltage	V_N	f=10Hz to 100KHz,T_A=+25°C			52		μV/Vo
Ripple Rejection	RR	f=120Hz Vi=11.5V to 21.5V		56	73		dB
Dropout Voltage	VDrop	Io=1A, T_J=+25°C			2		V
Short Circuit Current	I_{SC}	Vi=35V, T_A=+25°C			230		mA
Peak Current	I_{PK}	T_J=+25°C			2.2		A

*Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

D7809D Electrical Characteristics

(Refer to the test circuit, -40°C＜T_J＜125°C ,Io=500mA, Vi=15V, Ci=0.33μF, Co=0.1μF, unless otherwise specified

Characteristics	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	Vo	T_J=+25°C		8.68	9.0	9.32	V
		5.0mA≤Io≤1.0A,Po≤15W Vi=11.5V to 26V		8.55	9.0	9.45	
Line Regulation*	Regline	T_J=+25°C	Vi=11.5V to 26V		5.0	150	mV
			Vi=12.5V to 18V		2.0	80	
Load Regulation*	Regload	T_J=+25°C	Io=5.0mA to 1.2A		10	160	mV
			Io=250mA to 600mA		5.0	80	
Quiescent Current	I_Q	T_J=+25°C			5.0	8.0	mA
Quiescent Current Change	ΔI_Q	Io=5.0mA to 1.0A			0.05	0.5	mA
		Vi=11.5V to 26V			0.5	1.0	
Output Voltage Drift	$\Delta Vo/\Delta T$	Io=5.0mA			-0.8		mV/°C
Output Noise Voltage	V_N	f=10Hz to 100KHz,T_A=+25°C			52		μV/Vo
Ripple Rejection	RR	f=120Hz Vi=11.5V to 21.5V		56	73		dB
Dropout Voltage	VDrop	Io=1A, T_J=+25°C			2		V
Short Circuit Current	I_{SC}	Vi=35V, T_A=+25°C			230		mA
Peak Current	I_{PK}	T_J=+25°C			2.2		A

*Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

D7812D Electrical Characteristics

(Refer to the test circuit, -40°C＜T_J＜125°C,Io=500mA, Vi=19V, Ci=0.33μF, Co=0.1μF, unless otherwise specified

Characteristics	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	Vo	T_J=+25°C		11.5	12	12.5	V
		5.0mA≤Io≤1.0A,Po≤15W Vi=14.5V to 27V		11.4	12	12.6	
Line Regulation*	Regline	T_J=+25°C	Vi=14.5V to 30V		10	240	mV
			Vi=16V to 22V		3.0	120	
Load Regulation*	Regload	T_J=+25°C	Io=5.0mA to 1.2A		11	240	mV
			Io=250mA to 600mA		5.0	120	
Quiescent Current	I_Q	T_J=+25°C			5.1	8.0	mA
Quiescent Current Change	ΔI_Q	Io=5.0mA to 1.0A			0.1	0.5	mA
		Vi=14.5V to 30V			0.5	1.0	
Output Voltage Drift	$\Delta Vo/\Delta T$	Io=5.0mA			-1		mV/°C
Output Noise Voltage	V_N	f=10Hz to 100KHz,T_A=+25°C			76		μV/Vo
Ripple Rejection	RR	f=120Hz Vi=15V to 25V		55	71		dB
Dropout Voltage	VDrop	Io=1A, T_J=+25°C			2		V
Short Circuit Current	I_{SC}	Vi=35V, T_A=+25°C			230		mA
Peak Current	I_{PK}	T_J=+25°C			2.2		A

*Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

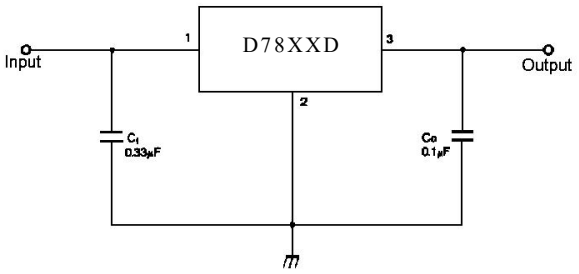
D7815D Electrical Characteristics

(Refer to the test circuit, -40°C＜T_J＜125°C ,Io=500mA, Vi=23V, Ci=0.33μF, Co=0.1μF, unless otherwise specified

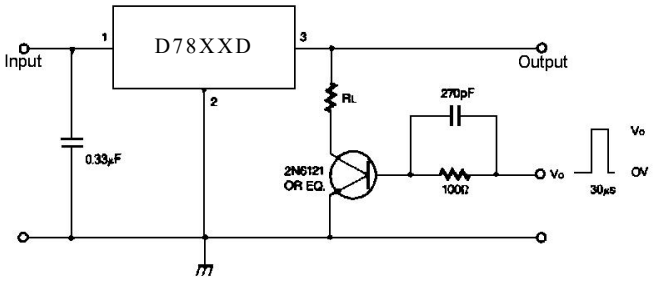
Characteristics	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	Vo	T_J=+25°C		14.4	15	15.6	V
		5.0mA≤Io≤1.0A,Po≤15W Vi=17.5V to 30V		14.25	15	15.75	
Line Regulation*	Regline	T_J=+25°C	Vi=17.5V to 30V		11	300	mV
			Vi=20V to 26V		3.0	150	
Load Regulation*	Regload	T_J=+25°C	Io=5.0mA to 1.2A		12	300	mV
			Io=250mA to 600mA		4.0	150	
Quiescent Current	I_Q	T_J=+25°C			5.2	8.0	mA
Quiescent Current Change	ΔI_Q	Io=5.0mA to 1.0A				0.5	mA
		Vi=17.5V to 30V				1.0	
Output Voltage Drift	$\Delta Vo/\Delta T$	Io=5.0mA			-1		mV/°C
Output Noise Voltage	V_N	f=10Hz to 100KHz,T_A=+25°C			90		μV/Vo
Ripple Rejection	RR	f=120Hz Vi=18.5V to 28.5V		54	70		dB
Dropout Voltage	VDrop	Io=1A, T_J=+25°C			2		V
Short Circuit Current	I_{SC}	Vi=35V, T_A=+25°C			250		mA
Peak Current	I_{PK}	T_J=+25°C			2.2		A

*Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

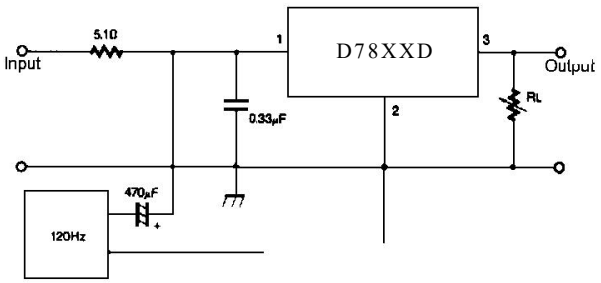
Application Circuit



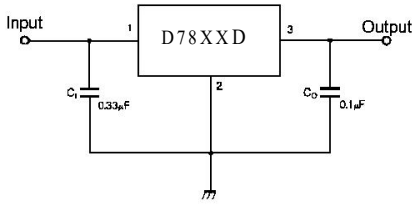
DC Parameters



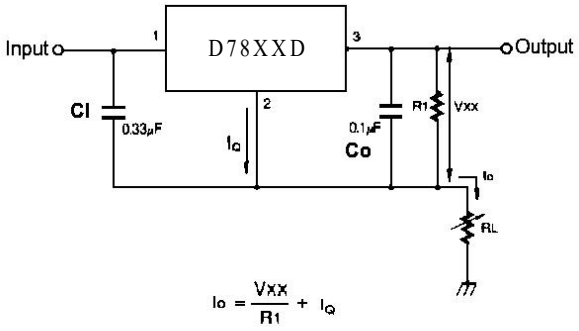
Load Regulation



Ripple Rejection



Fixed Output Regulator



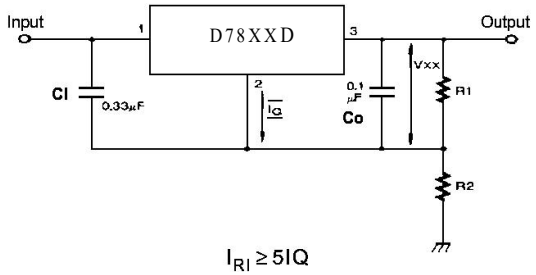
Constant Current Regulator

Notes:

(1) To specify an output voltage. substitute voltage value for "XX." A common ground is required between the input and the Output voltage. The input voltage must remain typically 2.0V above the output voltage even during the low point on the input ripple voltage.

(2) Ci is required if regulator is located an appreciable distance from power Supply filter.

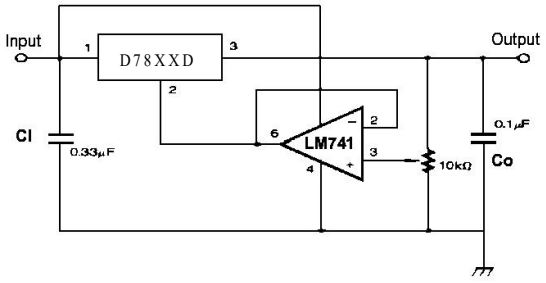
(3) Co improves stability and transient response.



$I_{RI} \geq 5IQ$

$V_O = V_{XX}(1+R_2/R_1)+I_QR_2$

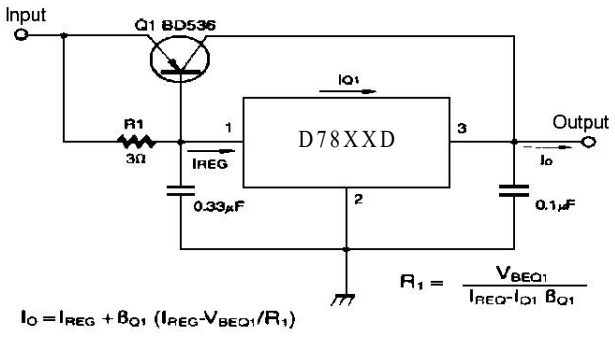
Circuit for Increasing Output Voltage



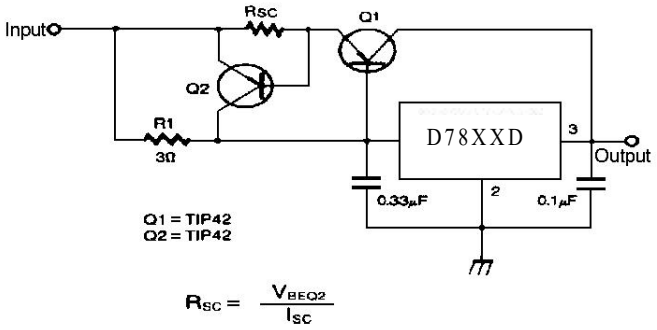
$I_{RI} \geq 5\ I_Q$

$V_O = V_{XX}(1+R_2/R_1)+I_QR_2$

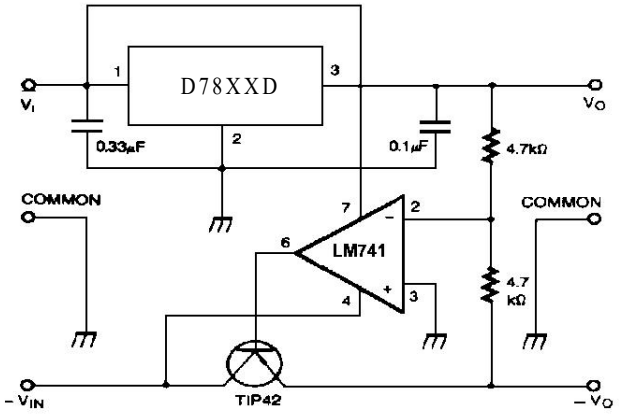
Adjustable Output Regulator (7 to 30V)



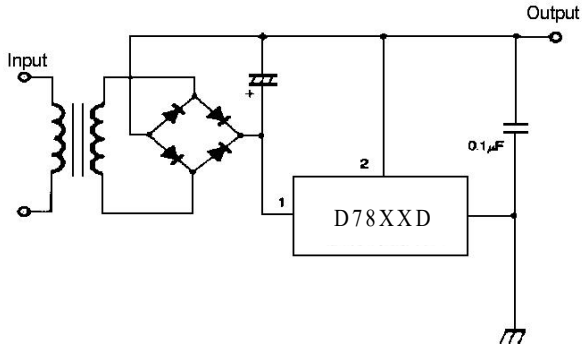
High Current Voltage Regulator



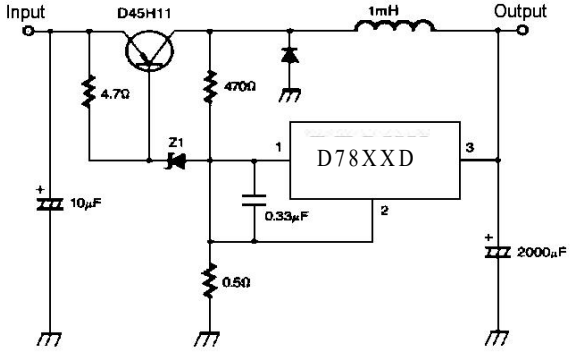
High Output Current with Short Circuit Protection



Tracking Voltage Regulator

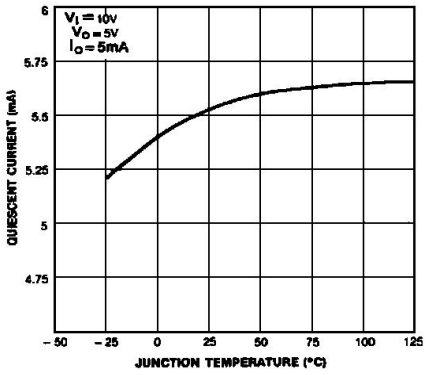


Negative Output Voltage Circuit

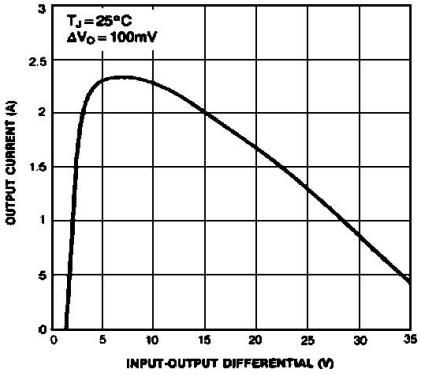


Switching Regulator

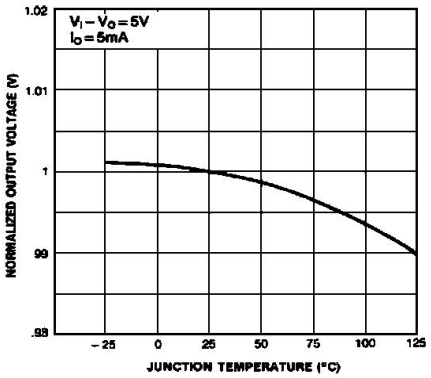
Characteristics Curves



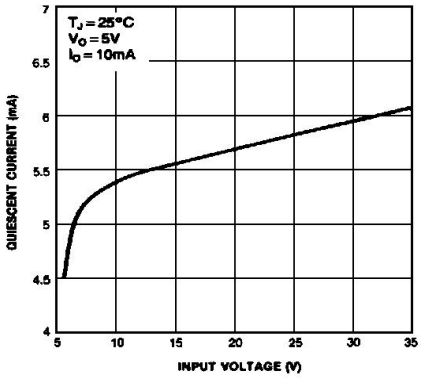
Quiescent Current



Peak Output Current



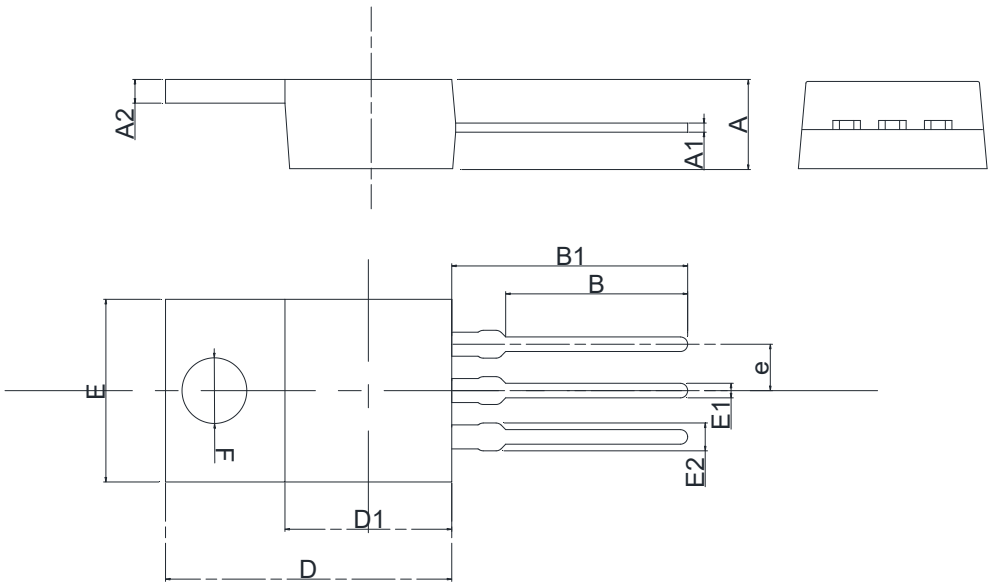
Output Voltage



Quiescent Current

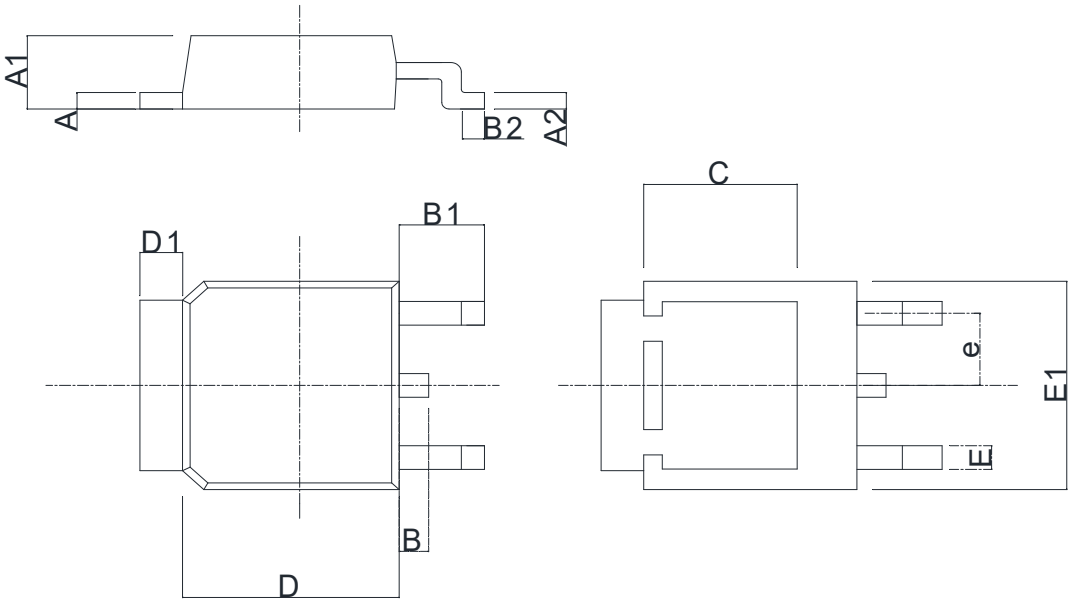
Outline Dimensions

TO220-3



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.300	4.800	0.169	0.189
A1	0.340	0.600	0.013	0.023
A2	1.220	1.400	0.047	0.055
B	9.460	10.380	0.372	0.408
B1	12.880	13.760	0.507	0.541
D	14.410	15.900	0.567	0.626
D1	8.000	9.000	0.314	0.354
E	9.700	10.400	0.381	0.409
E1	0.700	0.900	0.027	0.036
E2	1.220	1.400	0.048	0.055
e	2.540（BSC）		0.984（BSC）	
F	Φ 3.800	Φ 3.900	Φ 0.149	Φ 0.153

TO252-2



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.470	0.570	0.018	0.023
A1	2.220	2.380	0.087	0.094
A2	0.470	0.570	0.018	0.023
B	0.820	0.840	0.032	0.033
B1	2.380	2.480	0.093	0.098
B2	0.500	0.520	0.019	0.021
C	4.250	4.450	0.167	0.176
D	6.000	6.200	0.236	0.245
D1	1.150	1.250	0.045	0.050
E	0.650	0.850	0.025	0.034
E1	6.450	6.750	0.253	0.266
e	2.285（BSC）		0.090（BSC）	

Statements

- Silicore Technology reserves the right to make changes without further notice to any products or specifications herein. Before customers place an order, customers need to confirm whether datasheet obtained is the latest version, and to verify the integrity of the relevant information.

- Failure or malfunction of any semiconductor products may occur under particular conditions, customers shall have obligation to comply with safety standards when customers use Silicore Technology products to do their system design and machine manufacturing, and take corresponding safety measures in order to avoid potential risk of failure that may cause personal injury or property damage.

- The product upgrades without end, Silicore Technology will wholeheartedly provide customers integrated circuits that have better performance and better quality.